

Wide input voltage range SEPIC LED driver using ZXLD1321 with external power switch

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Introduction

Some LED lighting applications like the solar and automotive system, require an LED driver with a wide input voltage range where the LED voltage falls between minimum and maximum input voltage. In this case, neither boost nor buck topology would be a suitable solutions. SEPIC (Single Ended Primary Inductance Converter) resolves this issue and provide reasonable efficiency with relatively simple topology.

The following is a design example of a SEPIC LED driver which is capable of driving multi-chip LEDs with forward voltage up to 17V and LED current of 1A. The input voltage is wide with range from 8V to 30V.

1A Multi-chips LED driver with external SEPIC MOSFET switch

Figure 1 and Table 1 show the schematic and bill of materials of the design respectively.



Figure 1 - Schematic

Ref No.	Value	Part No.	Manufacturer	Note
U1	LED Driver IC	ZXLD1321	Diodes Zetex	www.diodes.com
				www.zetex.com
Q1	60V 10A Mosfet	ZXMN6A25K	Diodes Zetex	www.diodes.com
				www.zetex.com
Q2	Gate Driver Pairs	ZXTC2045	Diodes Zetex	www.diodes.com
		7/7/0004		www.zetex.com
Q3	50V NPN	ZXTN2031	Diodes Zetex	www.diodes.com
D1	100V/EA Cobottler		Diadaa Zatay	www.zetex.com
	Dootifier	FD35100H	Diddes Zelex	www.ulodes.com
D2	100V 1A Rectifier	S1B	Diodes Zetex	www.zetex.com
02		015	Diodes Zelex	
Z1	12V 350mW Zener	BZX84C12	Diodes Zetex	www.diodes.com
				www.zetex.com
Z2	18V 350mW Zener	BZX84C18	Diodes Zetex	www.diodes.com
				www.zetex.com
L1	22uH 5.2A SEPIC	NPIS25DW220MTRF	NIC Components	www.niccomp.com
	Inductor	744870220	Wurth Electronik	www.we-online.com
		MSD1278-223ML	Coilcraft	www.coilcraft.com
C1	10nF 50V	NMC0603X7R103K50TRPF	NIC Components	www.niccomp.com
	SMD 0603	GRM188R71E103KA01	Murata	www.murata.com
C2 C15	47nF 50V	NMC0603X7R473K50TRPF	NIC Components	www.murata.com
	SMD 0603	GRM188R71E473KA01	Murata	
C5	470uF 50V	Generic Electrolytic		
C3 C4	4.7uF 50V X7R	GRM31CR71H475KA12	Murata	www.murata.com
C6 C7	SMD 1206			
C8 C9				
C10 C11				
C12 C13				
C14				
R1 R1*	200mΩ	NCST12GR200GTRF	NIC Components	www.niccomp.com
		SMD 1206		
R2 R2*	20mΩ	SMD 1206		
R3	0Ω	SMD 0805 / 0603		
R4	1.2ΚΩ	SMD 0805 / 0603		
R5	33Ω	SMD 0805 / 0603		
R6	18Ω	SMD 0805 / 0603		
R7	10Ω	SMD 0805 / 0603		
R8	4.7ΚΩ	SMD 0805 / 0603		
R9	2.7ΚΩ	SMD 0805 / 0603		

Table 1 - Bill of materials

Circuit description

In this design, the ZXLD1321 is used as an LED driver controller to drive the MOSFET power switch through a ZXTC2045 gate drive transistor pair.

Although the input voltage rating of ZXLD1321 is 12V, by using an external 60V Mosfet power switch (ZXMN6A25K) and a simple 12V regulator formed by Q3 (ZXTN2031) and Z1, the system could operate up to 30V supply voltage with absolute maximum rating of 40V.

The SEPIC power stage is formed by Q1, D1, L1, L1' and C6 to C13. The same inductance is used for both L1 and L1' such that a coupled inductor can also be used. Instead of using two inductors for the power stage, a single standard coupled inductor is used to minimize the component count.

The output of the SEPIC stage is connected to the LEDs through the current sensing resistor R1. The voltage drop across R1 provides feedback to the LED controller IC and the sensing threshold is 100mV. Since the rated voltage of ZXLD1321's MVIN and MLOAD pin are limited to 18V, the system is capable of driving LEDs with total LED voltage below 18V. To prevent MVIN and MLOAD pins from over-voltage, Z2 and Q4 formed a voltage detection circuit which will pull down the ADJ pin. This will shutdown the driver IC whenever the LED voltage is above 18V.

Design Considerations

Since the voltage spike caused by the high switching current and stray inductance of PCB's copper track would be high compared to the low I_{SENSE} voltage threshold of ZXLD1321 which is below 55mV, RC filter formed by C2 and R5 is used to prevent false triggering of ISENSE pin. i.e. C2 should be placed as close as possible between the ISENSE pin and the exposed GND pad of the IC.

In SEPIC design, high ripple current appears at the output filtering capacitor (C10 – C13) and the SEPIC coupling capacitor (C6 - C9). Hence, a low ESR capacitor with an appropriate ripple current rating should be used. In this design, we recommend use of a standard X7R ceramic SMD capacitor working in parallel rather than the specialized pulse capacitor.

Performance

The typical efficiency throughout the input voltage range is shown in Figure 2 with average efficiency of 85%.

The line regulation of LED current is shown in Figure 3 with line regulation better than 3%.

Typical performance graphs



Figure 2



Figure 3

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Conclusion

The ZXLD1321 can be used in SEPIC mode to produce a high buck-boost LED driver with scalable output current capability at an efficiency of around 85%. The input voltage can be between 8 and 30V but the number of LEDs must be limited to ensure the output voltage is less than 17V.

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